

March 2007



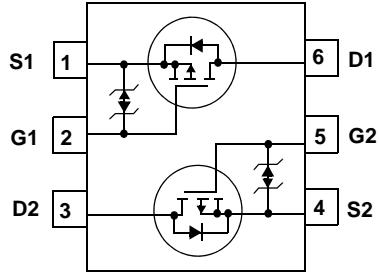
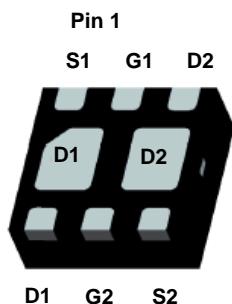
# FDMA1023PZ

## Dual P-Channel PowerTrench® MOSFET

### -20V, -3.7A, 72mΩ

#### Features

- Max  $r_{DS(on)}$  = 72mΩ at  $V_{GS} = -4.5V$ ,  $I_D = -3.7A$
- Max  $r_{DS(on)}$  = 95mΩ at  $V_{GS} = -2.5V$ ,  $I_D = -3.2A$
- Max  $r_{DS(on)}$  = 130mΩ at  $V_{GS} = -1.8V$ ,  $I_D = -2.0A$
- Max  $r_{DS(on)}$  = 195mΩ at  $V_{GS} = -1.5V$ ,  $I_D = -1.0A$
- Low profile - 0.8 mm maximum - in the new package MicroFET 2x2 mm
- RoHS Compliant



#### MOSFET Maximum Ratings $T_A = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DS}$	Drain to Source Voltage	-20	V
$V_{GS}$	Gate to Source Voltage	$\pm 8$	V
$I_D$	Drain Current -Continuous (Note 1a)	-3.7	A
	-Pulsed	-6	
$P_D$	Power Dissipation (Note 1a)	1.5	W
	(Note 1b)	0.7	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	°C

#### Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance for Single Operation, Junction to Ambient (Note 1a)	86	°C/W
$R_{\theta JA}$	Thermal Resistance for Single Operation, Junction to Ambient (Note 1b)	173	
$R_{\theta JA}$	Thermal Resistance for Single Operation, Junction to Ambient (Note 1c)	69	
$R_{\theta JA}$	Thermal Resistance for Single Operation, Junction to Ambient (Note 1d)	151	

#### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
023	FDMA1023PZ	MicroFET 2X2	7"	8mm	3000 units

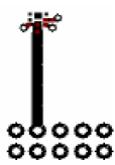


**Notes:**

- 1:  $R_{QJA}$  is determined with the device mounted on a 1 in<sup>2</sup> oz. copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{QJC}$  is guaranteed by design while  $R_{QJA}$  is determined by the user's board design.
- (a)  $R_{QJA} = 86^\circ\text{C}/\text{W}$  when mounted on a 1in<sup>2</sup> pad of 2 oz copper, 1.5" x 1.5" x 0.062" thick PCB
  - (b)  $R_{QJA} = 173^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper
  - (c)  $R_{QJA} = 69^\circ\text{C}/\text{W}$  when mounted on a 1in<sup>2</sup> pad of 2 oz copper, 1.5" x 1.5" x 0.062" thick PCB.
  - (d)  $R_{QJA} = 151^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper.



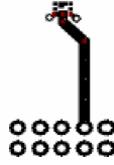
a)86°C/W  
when mounted  
on a 1in<sup>2</sup> pad of  
2 oz copper.



b)173°C/W  
when mounted  
on a minimum  
pad of 2 oz  
copper.



c)69°C/W when  
mounted on a  
1in<sup>2</sup> pad of 2 oz  
copper.



d)151°C/W  
when mounted  
on a minimum  
pad of 2 oz  
copper.

- 2: Pulse Test : Pulse Width < 300us, Duty Cycle < 2.0%

### Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

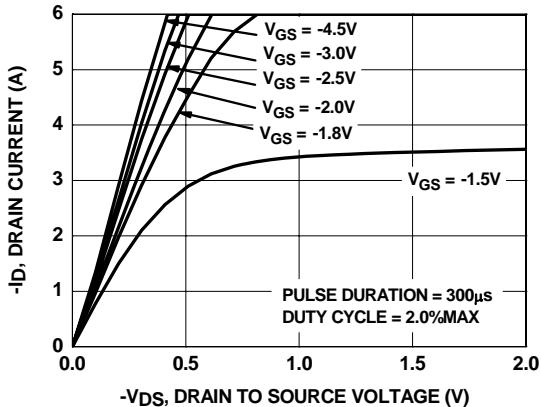


Figure 1. On Region Characteristics

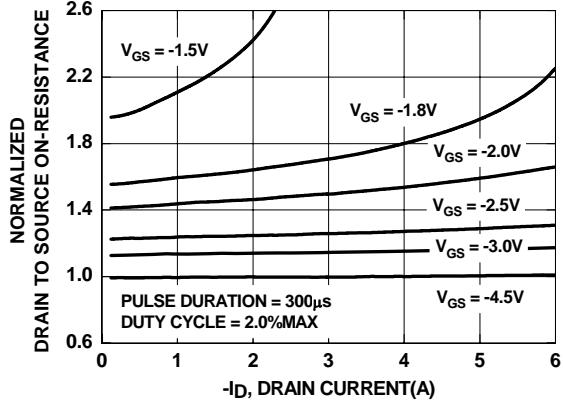


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

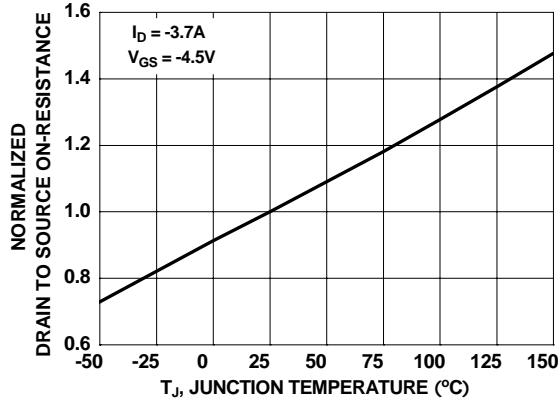


Figure 3. Normalized On-Resistance vs Junction Temperature

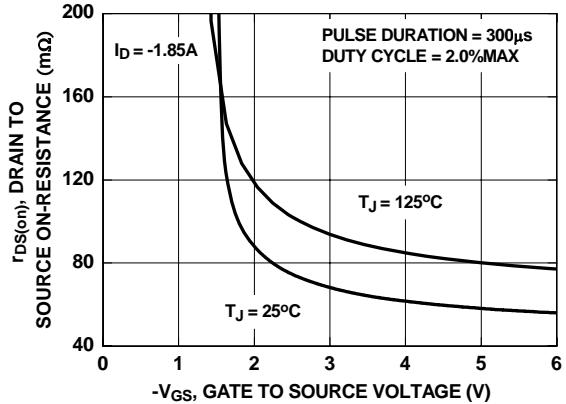


Figure 4. On-Resistance vs Gate to Source Voltage

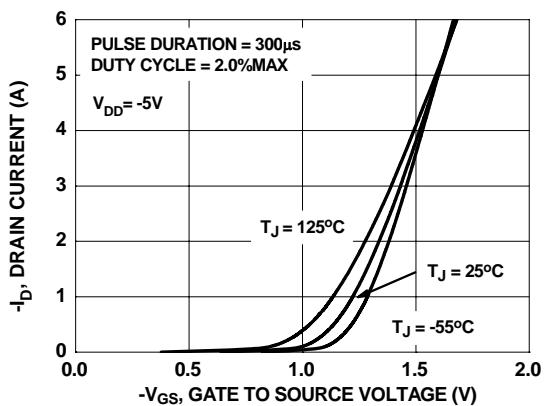


Figure 5. Transfer Characteristics

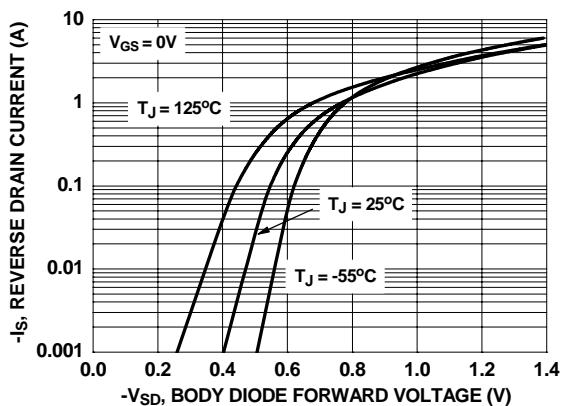


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

**Typical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted

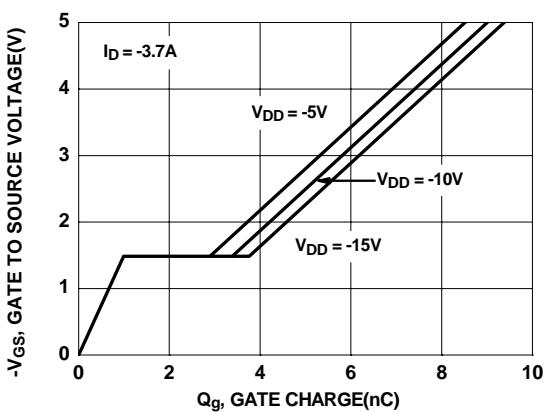


Figure 7. Gate Charge Characteristics

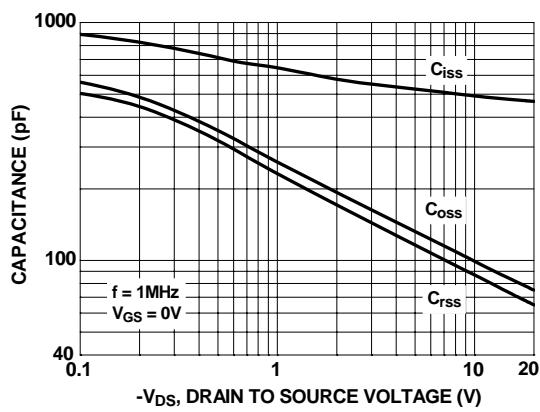


Figure 8. Capacitance Characteristics

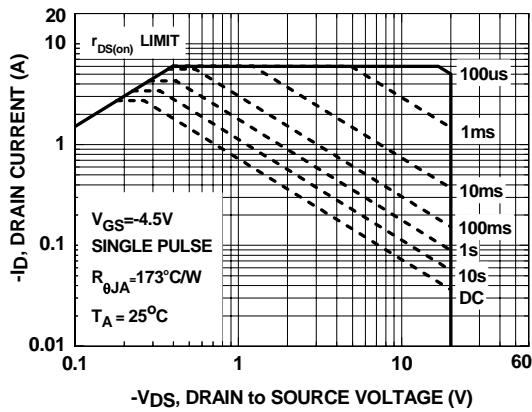


Figure 9. Forward Bias Safe Operating Area

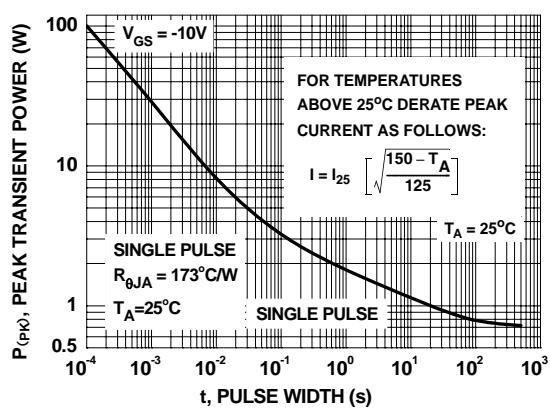


Figure 10. Single Pulse Maximum Power Dissipation

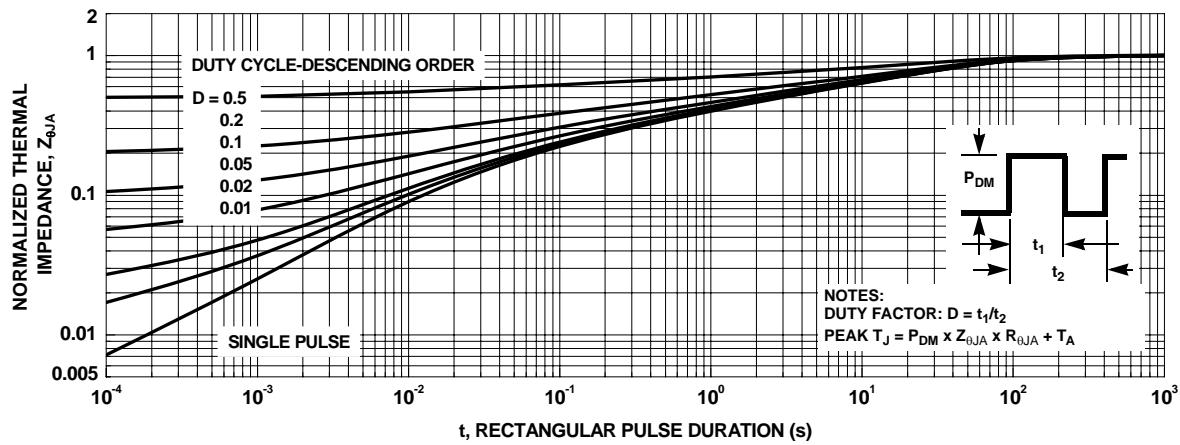
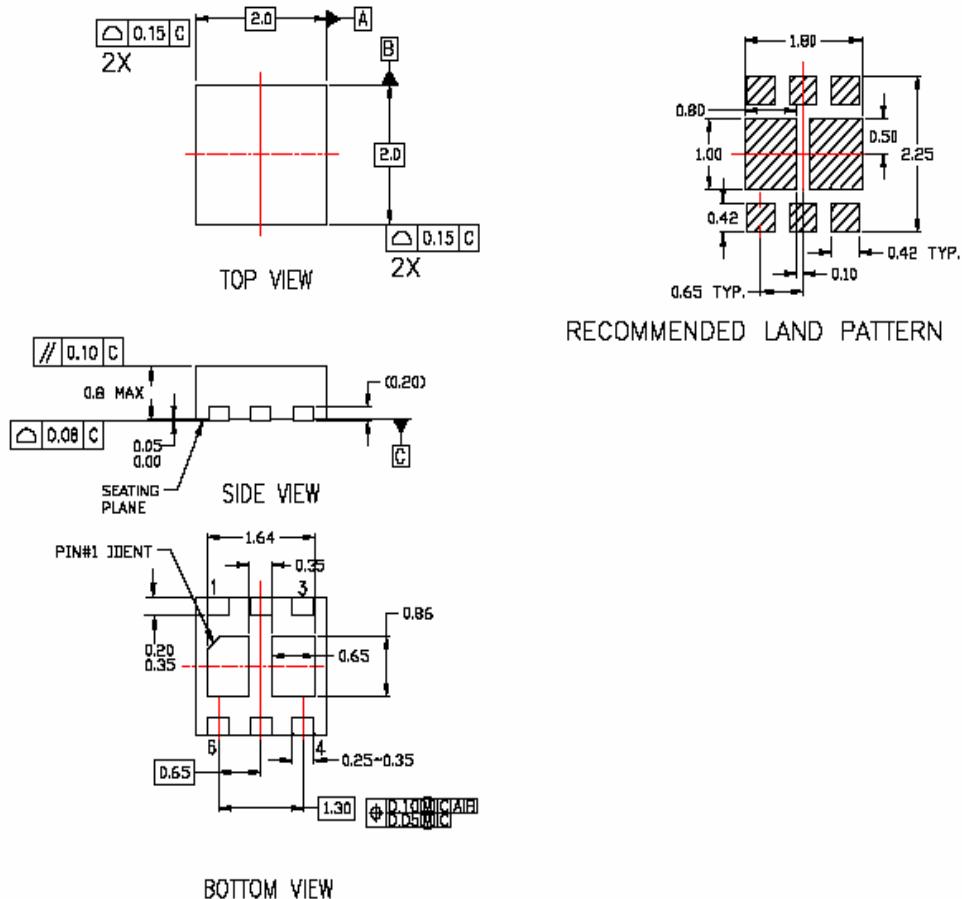


Figure 11. Transient Thermal Response Curve



**NOTES:**

- CONFORMS TO JEDEC REGISTRATION MO-229,  
VARIATION VCCC, DATED 11/2001
- DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS AND TOLERANCES PER  
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Rev. I24